# BYG22A, BYG22B, BYG22D

Vishay General Semiconductor

# Ultrafast Avalanche SMD Rectifier



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DO-214AC (SMA)

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2.0 A				
V <sub>RRM</sub>	50 V, 100 V, 200 V				
I <sub>FSM</sub>	35 A				
I <sub>R</sub>	1.0 µA				
V <sub>F</sub> at I <sub>F</sub>	1.1 V				
t <sub>rr</sub>	25 ns				
E <sub>R</sub>	20 mJ				
T <sub>J</sub> max.	150 °C				
Package	DO-214AC (SMA)				
Diode variations	Single die				

### **FEATURES**

- Low profile package
- · Ideal for automated placement
- Glass passivated pellet chip junction
- Low reverse current
- Low forward voltage
- Soft recovery characteristic
- · Ultra fast reverse recovery time
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **TYPICAL APPLICATIONS**

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, automotive, and telecommunication.

### **MECHANICAL DATA**

Case: DO-214AC (SMA) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 gualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	BYG22A	BYG22B	BYG22D	UNIT	
Device marking code		BYG22A	BYG22B	BYG22D		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	V	
Average forward current	I <sub>F(AV)</sub>	2.0			А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	35			A	
Pulse energy in avalanche mode, non repetitive (inductive load switch off) $I_{(BR)R} = 1 \text{ A}, T_J = 25 ^{\circ}\text{C}$	E <sub>R</sub>	20			mJ	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150			°C	



COMPLIANT



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	BYG22A	BYG22B	BYG22D	UNIT
Maximum instantaneous forward voltage	I <sub>F</sub> = 1.0 A	T 05 %0	V <sub>F</sub> <sup>(1)</sup>	1.0			v
	I <sub>F</sub> = 2.0 A	T <sub>J</sub> = 25 °C		1.1			
Maximum reverse current	V _ V	T <sub>J</sub> = 25 °C T <sub>J</sub> = 100 °C		1			μΑ
	$V_{R} = V_{RRM}$		IR	10			
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t <sub>rr</sub>	25		ns	

#### Note

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	BYG22A BYG22B BYG22D			UNIT
Maximum thermal resistance, junction to lead, $T_L = const.$	$R_{ ext{ heta}JL}$	25			°C/W
Maximum thermal resistance, junction to ambient	$R_{\theta JA}$ <sup>(1)</sup>	150			
	R <sub>0JA</sub> <sup>(2)</sup>	125		°C/W	
	R <sub>0JA</sub> <sup>(3)</sup>		100		

#### Notes

<sup>(1)</sup> Mounted on epoxy-glass hard tissue

<sup>(2)</sup> Mounted on epoxy-glass hard tissue, 50 mm<sup>2</sup> 35 µm Cu

<sup>(3)</sup> Mounted on Al-oxide-ceramic (Al<sub>2</sub>O<sub>3</sub>), 50 mm<sup>2</sup> 35 µm Cu

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
BYG22A-E3/TR	0.064	TR	1800	7" diameter plastic tape and reel	
BYG22A-E3/TR3	0.064	TR3	7500	13" diameter plastic tape and reel	
BYG22AHE3/TR <sup>(1)</sup>	0.064	TR	1800	7" diameter plastic tape and reel	
BYG22AHE3/TR3 <sup>(1)</sup>	0.064	TR3	7500	13" diameter plastic tape and reel	

#### Note

(1) AEC-Q101 qualified



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### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

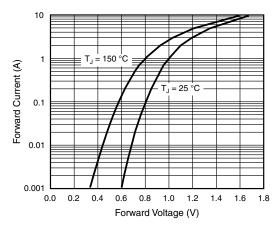


Fig. 1 - Forward Current vs. Forward Voltage

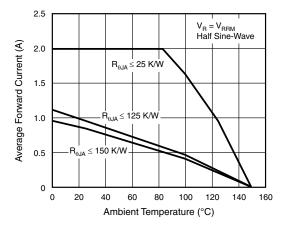


Fig. 2 - Max. Average Forward Current vs. Ambient Temperature

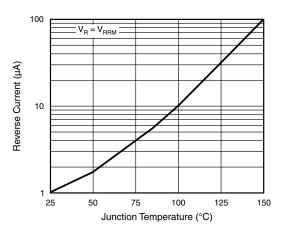


Fig. 3 - Reverse Current vs. Junction Temperature

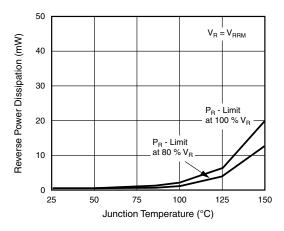


Fig. 4 - Max. Reverse Power Dissipation vs. Junction Temperature

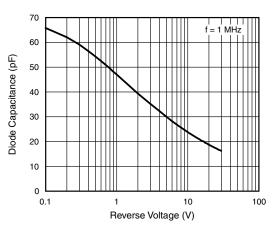


Fig. 5 - Diode Capacitance vs. Reverse Voltage

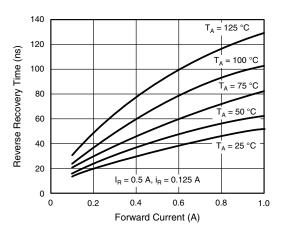


Fig. 6 - Max. Reverse Recovery Time vs. Forward Current

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#### 60 T<sub>A</sub> = 125 °C Reverse Recovery Charge (nC) 50 T<sub>A</sub> = 100 °C 40 = 75 °C 30 TA = 50 °C 20 . = 25 °C T۸ 10 I<sub>R</sub> = 0.5 A, i<sub>R</sub> = 0.125 A 0 0.2 0.4 0.6 0.8 0 1.0 Forward Current (A)

Fig. 7 - Max. Reverse Recovery Charge vs. Forward Current

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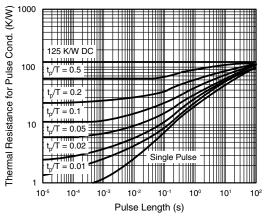
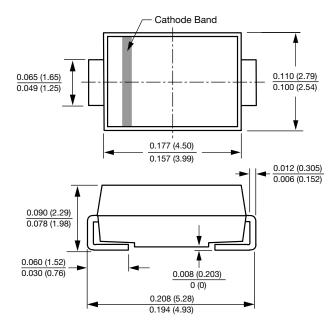


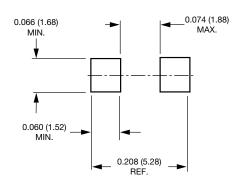
Fig. 8 - Thermal Response

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



### DO-214AC (SMA)

**Mounting Pad Layout** 





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